NPN Epitaxial Planar Silicon Transistor



CPH6221

DC / DC Converter Applications

Applications

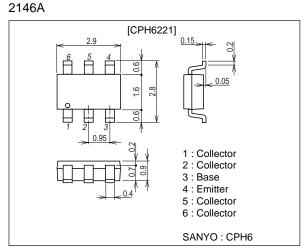
• Relay drivers, lamp drivers, motor drivers, strobe.

Features

- · Adoption of MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- · High allowable power dissipation.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		15	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		3	А
Collector Current (Pulse)	ICP		5	А
Base Current	IB		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	VCB=12V, IE=0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			0.1	μΑ
DC Current Gain	hFE	V _{CE} =2V, I _C =500mA	200		560	
Gain-Bandwidth Product	fT	VCE=2V, IC=500mA		350		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		23		pF

Marking : CV

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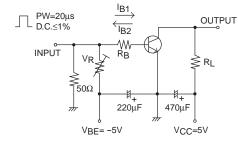
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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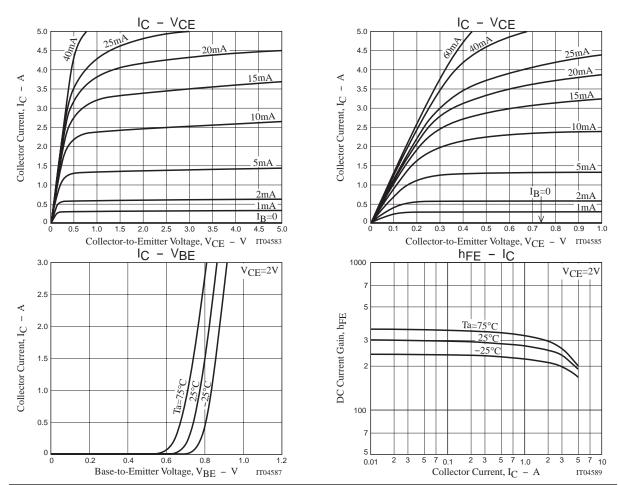
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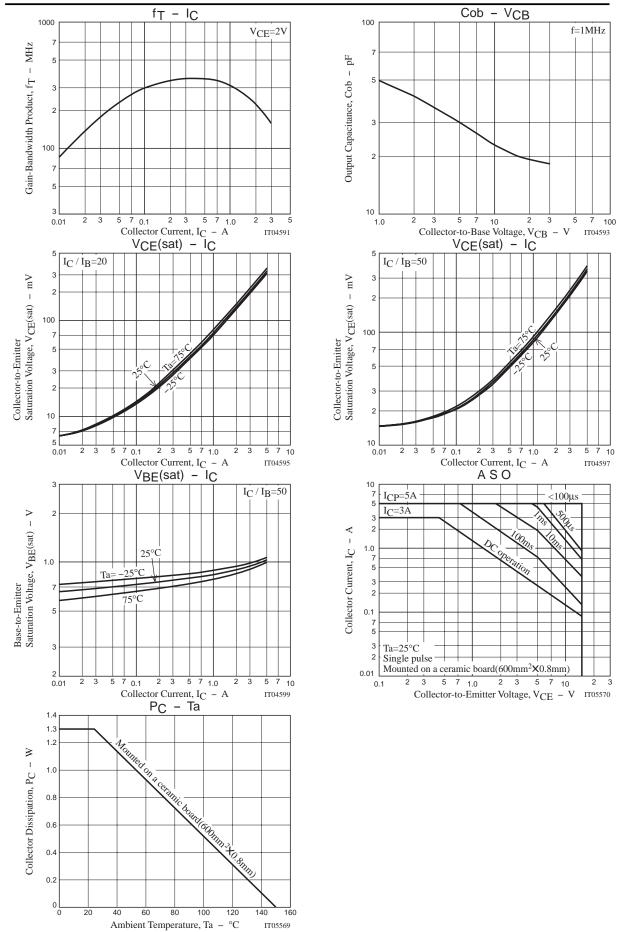
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=1.5A, IB=30mA		115	175	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=1.5A, IB=30mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		210		ns
Fall Time	tf	See specified Test Circuit.		11		ns

Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=1.5A$





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